# **HT MICRON**



Sigfox® Monarch RF Transceiver System-in-Package

#### **OVERVIEW**

The iMCP – HT32SX is a Multicomponent Integrated Circuit (MCO) designed to provide a ready-to-use connectivity solution for Internet of Things (IoT) applications. It provides both uplink (transmit) and downlink (receive) communications, and it is the first HT Micron product in a new family of non-memory components. Its small dimensions, high performance and low power consumption targets the best experience for IoT developers. It features an ARM Cortex M0+ 32bit (STM32L052x8) and the S2-LP low power transceiver from ST Microelectronics combined with the SKY66420 from Skyworks Solutions which provide all the performance advantages, integration and convenience of advanced semiconductor packaging technology into a single chip.

#### **FEATURES**

- Key features
  - Enables operations in the SIGFOX™ network
  - Multizone worldwide operation MONARCH feature
  - ARM Cortex M0+ 32bit STM32L052x8 MCU
  - Integrated 50 MHz crystal
  - 64 KB flash Other options will be available on demand
  - 8 KB RAM
  - TX output power up to +24 dBm
  - RX sensitivity: -128 dBm\*
- Power consumption
  - 18 mA RX
  - 160 mA TX @24 dBm, 902.2MHz
- RF
  - S2-LP Transceiver STMicroelectronics
  - SKY66420-11 Front-End Module
  - Frequency bands:
    - o 413-479 MHz
    - o 452-527 MHz
    - o 826-958 MHz
    - o 904-1055 MHz
  - Modulation schemes:
    - o DBPSK, 2(G)FSK, OOK, ASK
  - Data Rate:
    - o Up to region: 100bps or 600bps

#### \*Expected performance





#### **INTERFACES**

- Up 21 General-Purpose Input/Output (GPIO) pins, with configurable pull-up/pull-down resistors
- 12-bit ADC
- 12-bit 1 channel DAC
- 2 USART, LPUART, USB 2.0, I2C
- Single power supply: 2.7 V to 3.6 V
- Operating temperature range: -20°C to +75°C\*
- External antenna
- 13x13x1.35mm LGA 32 pads package
- Part number: HT32SX

#### **APPLICATIONS**

- Smart home
- Wireless alarm systems
- Manufacturing
- Agriculture
- Building automation
- Smart metering
- Smart lighting systems
- Smart grid monitoring

## **SUMMARY**

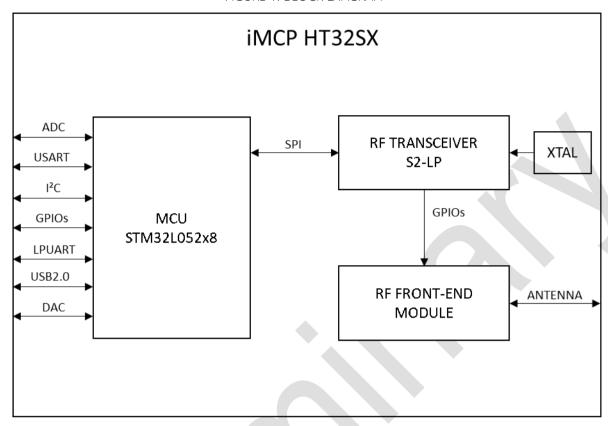
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# **DOCUMENT INFO**

 $This \ document \ provides \ information \ about \ iMCP \ HT32SX-Sigfox @\ Monarch\ RF\ Transceiver\ System-in-Package.$ 

# 1 BLOCK DIAGRAM

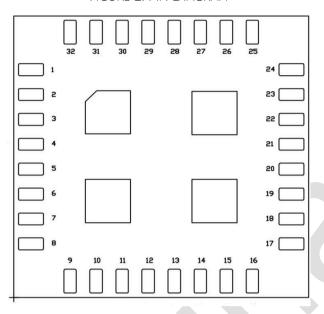
FIGURE 1: BLOCK DIAGRAM



## 2 PINOUT INFORMATION

## 2.1 Pin Diagram

Figure 2: Pin Diagram



# 2.2 Pin description

TABLE 1: LEGEND/ABBREVIATIONS USED IN PIN DESCRIPTION TABLE

Name	Abbreviation	Definition
	FT	5V tolerant I/O
	FTf	5V tolerant I/O, FM+ capable
I/O Structure	TC	Standard 3.3V I/O
	В	Dedicated BOOT0 pin
	RST	Bidirectional reset pin with embedded weak pull-up resistor

TABLE 2: PIN DESCRIPTION

Number	Symbol	Pin name	Pin Type	I/O Structure	Description
1	ANTENNA	ANTENNA	RF I/O	-	RF input and output signal
2	GND	GND	Ground	_	Exposed pad connected to the ground of
_	GIND	GIND	Ground		the application board
		USART1_CTS	Digital I/O		USART interface
3	MCLLDA11	USB_DM	Digital I/O		USB
3	MCU-PA11	COMP1_OUT	Analog O	- FT	Comparator output
		EVENT_OUT	Digital I/O		
4	MCU-PA9	USART1_TX	Digital I/O	FT	Serial wire
5	MCU-PA10	USART1_RX	Digital I/O	FT	Seriai Wire
		LPUART1_RX	Digital I/O		Low-power USART interface
6	MCU-PB11	TIM2_CH4	Digital I/O	FT	General-purpose timer
		EVENTOUT	Digital I/O		
-	MCLLDDO	ADC_IN0	Analog I	ГТ	ADC external input 0
/	MCU-PB0	VREF_OUT	Analog I/O	- FT	Output reference voltage

8	VDD_3.3V	VDD_3.3V	Power	_	3.3 V power supply
	VDD_3.5 V	USART1_CK	Digital I/O		USART interface
9	MCU-PA8	USB_CSR_SYNC	Digital I/O	FT	USB
J	1100-1710	EVENT_OUT	Digital I/O	''	COD
		ADC_IN5	Analog I		ADC external input 5
		TIM2_CH1	Digital I/O		General-purpose timer
10	MCU-PA5	TIM2_ETR	Digital I/O	TC	General-purpose timer
		COMP1_INM5	Analog I		Comparator input
		USART2_RX	Digital I/O		USART interface
		ADC IN3	Analog I		ADC external input 3
11	MCU-PA3	TIM2_CH4	Digital I/O	FT	General-purpose timer
		TIM21_CH2	Digital I/O		General-purpose timer
		USART2_RTS_DE	Digital I/O		USART interface
		ADC_IN1	Analog I		ADC external input 1
12	MCU-PA1	COMP1_INP	Analog I	FT	Comparator input
12	11001711	TIM21_ETR	Digital I/O	''	General-purpose timer
		EVENT OUT	Digital I/O		General parpose times
		LPUART1_TX	Digital I/O		USART interface
13	MCU-PB10	TIM2_CH3	Digital I/O	FT	General-purpose timer
		LPUART1_CTS	Digital I/O		USART interface
		ADC_IN6	Analog I		ADC external input 6
14	MCU-PA6	TIM22_CH1	Digital I/O	FT	General-purpose timer
	11001710	COMP1_OUT	Analog O		Comparator output
		EVENT_OUT	Digital I/O		Gen.parater Garpat
		USART2_CK	Digital I/O		USART interface
		ADC_IN4	Analog I		ADC external input 4
15	MCU-PA4	DAC_OUT	Analog O	TC	DAC analog output
		TIM22_ETR Digital I/O	General-purpose timer		
		COMP1_INM4	Analog I		Comparator input
	61.15				Exposed pad connected to the ground of
16	GND	GND	Ground	-	the application board
		USART2_TX	Digital I/O		USART interface
		ADC_IN2	Analog I		ADC external input 2
17	MCU-PA2	TIM21_CH1	Digital I/O	FT	General-purpose timer
		TIM2_CH3	Digital I/O		General-purpose timer
		WKUP1	Digital I		MCU external wakeup input
		ADC_IN0	Analog I		ADC external input 0
18	MCU-PA0	USART2_CTS	Digital I/O	TC	USART interface
		TIM2_CH1	Digital I/O		General-purpose timer
19	MCU- BOOT0	воото	Digital I	В	Boot selection
		I2C1_SMBA	Digital I/O		I2C interface
20	MCU-PB5	LPTIM1_IN1	Digital I/O	FT	Low-power timer
		TIM22_CH2	Digital I/O		General-purpose timer
					Exposed pad connected to the ground of
21	GND	GND	Ground		the application board
22	NRESET	NRESET	I/O	RST	Bidirectional reset pin with embedded weak pull-up resistor
		SWCLK	Digital O		Serial wire clock output
23	MCU-PA14	USART2_TX	Digital I/O	FT	USART interface
24	MCII DA42	SWDIO	Digital I/O		Serial wire
24	MCU-PA13	USB_NOE	Digital I/O	FT	USB

25	OSC32OUT	OSC32OUT		TC	External clock source pine	
26	OSC32IN	OSC32IN		FT	External clock source pins	
27	GND	GND	Ground	-	Exposed pad connected to the ground of the application board	
		LPUART1_RTS_DE	Digital I/O		Low-power USART interface	
28	MCU-PB1	ADC_IN9	Analog I	FT	ADC external input 9	
20	1100-111	VREF_OUT	Analog O		1.2 V VCO-LDO band-gap reference voltage decoupling	
		USART1_RX	Digital I/O		USART interface	
29	MCU-PB7	I2C1_SDA	Digital I/O	FTf	I2C interface	
		LPTIM1_IN2	Digital I/O		Low-power timer	
		USART1_TX	Digital I/O		USART interface	
30	MCU-PB6	I2C1_SCL	Digital I/O	FTf	I2C interface	
		LPTIM1_ETR	Digital I/O		Low-power timer	
		USART1_RTS_DE	Digital I/O		USART interface	
31	MCU-PA12	USB_DP	Digital I/O	FT	USB	
		EVENT_OUT	Digital I/O			
32	GND	GND	Ground		Exposed pad connected to the ground of the application board	

# 3 ELECTRICAL CHARACTERISTICS

## 3.1 General operating range

TABLE 3: GENERAL OPERATING RANGE

Parameter	Conditions	Min	Тур.	Max	Unit
Internal XTAL frequency	-	-	50	-	MHz
Supply voltage	-	2.7	3.3	3.6	V
Operating temperature	-	-20*	25*	75*	°C
Storage temperature	-	-	-	-	°C

<sup>\*</sup>Expected performance

# 3.2 MCU I/O port characteristics

TABLE 4: MCU I/O PORT CHARACTERISTICS

Symbol	Parameter	Conditions	Min	Тур.	Max	Unit
V	Input low level	TCFT, FTf, RST I/Os	-	-	0.3V <sub>DD</sub>	
V <sub>IL</sub>	voltage	BOOT0 pin	-	-	0.14V <sub>DD</sub>	
V <sub>IH</sub>	Input high level voltage	All I/Os	0.7 <i>V</i> <sub>DD</sub>	-	-	V
V.	I/O Schmitt trigger	Standard I/Os	-	10% V <sub>DD</sub>	-	
V <sub>hys</sub>	voltage hysteresis	BOOT0 pin	-	0.01	-	
		$V_{SS} < V_{IN} < V_{DD}$ All I/Os except PA11, PA12, BOOT0, FTf I/Os	-	-	+-50	
$I_{lkg}$	Input leakage current	$ m V_{SS} < V_{IN} < V_{DD}$ PA11 and PA12 I/Os	-	-	-50/+250	nA
		$V_{SS} < V_{IN} < V_{DD}$ FTf I/Os	-	-	+-100	

		$V_{VDD} < V_{IN} < 5V$ All I/Os except PA11, PA12, BOOT0, FTf I/Os	-	-	200	
		$V_{SS} < V_{IN} < 5V$ FTf I/Os	-	-	500	nA
		V <sub>ss</sub> < V <sub>in</sub> < 5V PA11, PA12, BOOT0	-	-	10	uA
$\mathbf{R}_{PU}$	Weak pull-up equivalent resistor	$V_{IN} = V_{SS}$	25	45	65	kΩ
$R_{PD}$	Weak pull-down equivalent resistor	$V_{IN} = V_{DD}$	25	45	65	kΩ
$C_{IO}$	I/O pin capacitance	-	-	5	-	рF

TABLE 5: OUTPUT VOLTAGE CHARACTERISTICS

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{OL}$	Output low level voltage for an I/O pin	CMOS port I <sub>IO</sub> =+8mA	-	0.4	
V <sub>OH</sub>	Output high level voltage for an I/O pin	$2.7 \text{V} < \text{V}_{DD} < 3.6 \text{V}$	<b>V</b> <sub>DD</sub> -0.4	-	
$V_{OL}$	Output low level voltage for an I/O pin	TTL port $I_{IO}$ =+8mA 2.7V < $V_{DD}$ < 3.6V	1	0.4	
V <sub>OH</sub>	Output high level voltage for an I/O pin	TTL port $I_{IO}$ = -6mA 2.7V < $V_{DD}$ < 3.6V	2.4	-	
$V_{OL}$	Output low level voltage for an I/O pin	$I_{IO}$ =+15mA 2.7V < $V_{DD}$ < 3.6V	-	1.3	V
V <sub>OH</sub>	Output high level voltage for an I/O pin	$I_{IO}$ = -15mA 2.7V < $V_{DD}$ < 3.6V	V <sub>DD</sub> -1.3	-	
$V_{OL}$	Output low level voltage for an I/O pin	$I_{IO}$ =+4mA 2.7V <v<sub>DD&lt; 3.6V</v<sub>	-	0.45	
V <sub>OH</sub>	Output high level voltage for an I/O pin	$I_{IO}$ = -4mA 2.7V < $V_{DD}$ < 3.6V	<b>V</b> <sub>DD</sub> -0.45	-	
V	Output low level voltage for an FTf I/O	$I_{IO}$ = +20mA 2.7V < $V_{DD}$ < 3.6V	-	0.4	
V <sub>OLFM+</sub>	pin in FM+ mode	$I_{IO}$ = 10mA 2.7V < $V_{DD}$ < 3.6V	-	0.4	

### 3.3 Power consumption

Characteristics measured over recommended operating conditions unless otherwise specified. Typical values are referred to 25 °C temperature, VDD = 3.3 V.

Table 6: Low-power state power consumption TA = 25 °C, VDD = 3.3 V, 50 MHz crystal oscillator.

Parameter	Conditions	Min	Тур.	Max	Unit
	Shutdown	-	-	-	nA
6 1	Standby	3.8	4.5	5	mA
Supply current	Sleep	-	-	-	uA
	Deep sleep	-	4	8	uA

TABLE 7: POWER CONSUMPTION IN RECEPTION TA = 25 °C, VDD = 3.3 V, FC = 905 MHz

Parameter	Conditions	Min	Тур.	Max	Unit
Supply current	RX @ -102	_	10		mΔ
Supply current	sensitivity level	_	18	-	mA mA

Table 8: Power consumption in transmission TA = 25 °C, VDD = 3.3 V, FC = 902.2 MHz

Parameter	Conditions	PA	Min	Тур.	Max	Unit
	TX @24 dBm on packet	ON	_	_	160	
Supply current	transmission				100	ma Λ
	TX @13 dBm					mA
	on packet	OFF	-	-	30	
	transmission					

#### 3.4 Clock source

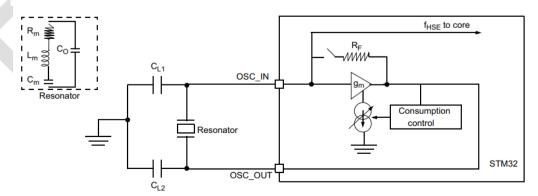
TABLE 9: 50 MHz Internal XTAL clock source characteristics

Parameter	Conditions	Min	Тур.	Max	Unit
Nominal frequency	-	-	50	-	MHz
Frequency tolerance	-20°C to 75 °C	-10	-	+10	ppm
Load capacitance	-	-	7	-	pF
Motional resistance (ESR)	-		-	60	Ω

#### 3.5 External clock resonator

The external clock resonator can be of high speed (1-25MHz) or low speed (32.768kHz), which can be connected to pins 25 and 26 of the iMCP HT32SX V2.2. The connection diagram is shown below. For CL1 and CL2, it is recommended to use high quality ceramic capacitors in the 5pF to 25 pF range (typ.), designed for high frequency applications, and selected to match the requirements of the crystal or resonator. These capacitors are usually of equal value with a rough estimate of 10 pF each. CL1 and CL2 includes PCB and the MCU pin capacitances.

FIGURE 3: EXTERNAL OSCILLATOR CIRCUIT DIAGRAM.



#### 4 RF CHARACTERISTICS

Table 10: Transceiver and Receiver Characteristics. TA =  $25^{\circ}$ C based on Characterization; not tested in Production. VDD = 3.3V; All RX measurements made at the antenna connector, to a bit error rate (BER) Limit of 1%. Lower frequencies update soon.

Parameter		Min	Тур.	Max	Unit
	TX	865	-	924	MHz
RF Frequency	RX	869	-	923	MHz
Tx max. output power		-	24	-	dBm
Tx power variation vs. temperature		-	-	-	dB
Emission 2 <sup>nd</sup> Harmonics (conducted)		-40.4	-47.3	-39.9	
Emission 3 <sup>rd</sup> Harmonics (conducted)		-50.5	-76.2	-55.0	dBc
Emission 4 <sup>th</sup> harmonic		-78.9	-78.6	-70.0	
<b>Data Rate</b> (for Sigfox Regions)	TX (RC1, RC3, RC5, RC6, RC7)	-	100		bps
	TX (RC2, RC4)	-	600	-	bps
	RX (All RCs)	-	600	-	bps
Antenna Load Impedance			50		Ohm
Rx Sensitivity (@600bps, GFSK)			-128*		dBm
Rx Spurious Emission (30MHZ~12.75GHZ)		-	-	-	dBm
Rx Blocking at 10MHz offset		1	-	-	dB
RSSI Resolution		-	-	-	dB

<sup>\*</sup>Expected performance

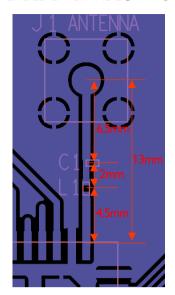
### 4.1 External impedance matching network

An external LC matching network is recommended to improve the output power level of the output signal in pin 1 (series inductor and shunt capacitor). The reference specifications for a reference FR4 1.6 mm 1 Oz copper printed circuit board (PCB) are shown below.

- SMD ceramic inductor: 5.6 nH, +-5% tolerance, 0402 size, PN L-07C5N6SV6, Johanson Technologies
- SMD ceramic capacitor: 4.7 pF, +-0.1pF tolerance, 0201 size, PN 250R05L4R7BV4S, Johanson Technologies

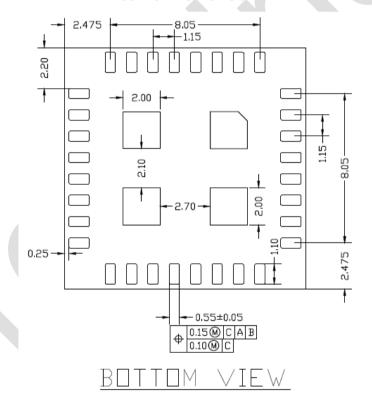
The reference PCB traces are shown in Figure 4 for an example of an output using an SMA connector. The trace width are the same as the pad width in the recommended footprint in section 6.

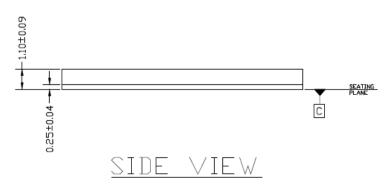
FIGURE 4: RECOMMENDED EXTERNAL LC MATCHING NETWORK LAYOUT.



### 5 PACKAGE OUTLINE

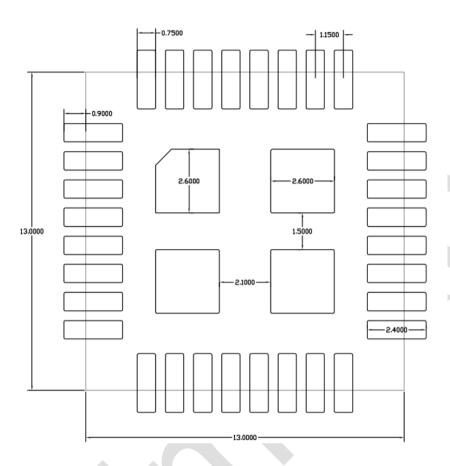
FIGURE 5: PACKAGE OUTLINE





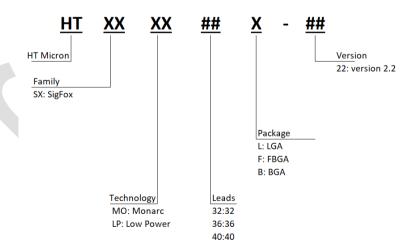
### 6 RECOMMENDED PCB FOOTPRINT

FIGURE 6: RECOMMENDED PCB FOOTPRINT



### 7 PART NUMBER

#### HTSXMO32L-22



## **8 ORDERING INFORMATION**

Table 11: Ordering information

	Package			
Type number	Name	Description	Version	
HTSXMO32L	iMCP HT32SX	SiP module in LGA package; body 13mm x 13mm	2.2	

# **ABBREVIATIONS**

TABLE 12: ABBREVIATIONS

Acronym	Description
ADC	Analog to Digital Converter
AES	Advanced Encryption Standard
API	Application Program Interface
CLK	Clock
EEPROM	Electrically-Erasable Programmable Read Only Memory
FIFO	First in First Out
GPIO	General Purpose Input Output
ID	Identification
IF	Intermediate frequency
Ю	Input Output
MSL	Moisture sensitivity level
PCB	Printed-Circuit Board
PHY	Physical
SPI-bus	Serial Peripheral Interface -bus
PWM	Pulse Width Modulation
RAM	Random Access Memory
RC	Remote Control
RF	Radio Frequency
RoHS	Restriction of Hazardous Substances
RSSI	Receive Signal Strength Indication
RX	Receiver
SCL	Serial Clock
SDA	Serial Data
TX	Transmitter

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measurements made at the antenna connector, to a bit error rate (BER) limit of 1%. Lower frequencies update soon	13

### **REVISION HISTORY**

Date	Version	Changes	Authors
13/04/2020	00	- Initial draft	HT Micron
05/08/2020	01	- Preliminary	HT Micron

### **CONTACT**

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